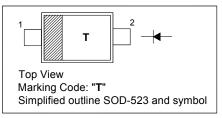
BAND SWITCHING DIODE

Applications

- · Low loss band switching in VHF television tuners
- Surface mount band-switching circuits

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings ($T_a = 25 \, ^{\circ}$ C)

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	35	V
Continuous Forward Current	I _F	100	mA
Power Dissipation (T _S = 90 °C)	P _{tot}	715	mW
Junction Temperature	TJ	- 65 to + 150	°C
Storage Temperature Range	Ts	- 65 to + 150	°C

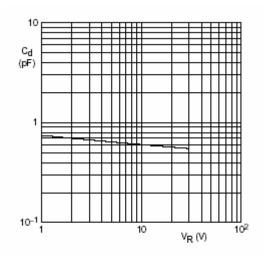
Characteristics at $T_a = 25$ °C

Parameter	Symbol	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F	1	V
Reverse Current at V _R = 25 V	I _R	50	nA
Diode Forward Resistance at $I_F = 2$ mA, $f = 100$ MHz	r _D	0.7	Ω
Capacitance at f = 1 MHz, V _R = 6 V	C _d	1.2	pF



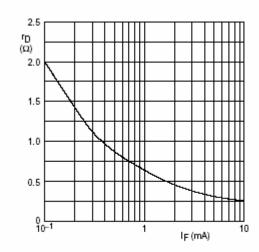






f = 1 MHz; T_I = 25 °C.

Fig. 1 Diode capacitance as a function of reverse voltage; typical values.



f = 100 MHz; T_I = 25 °C.

Fig. 2 Diode forward stance as a function of forward current; typical values.







PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523

